L Number	Hits	Search Text	DB	Time stamp
1	2876205	memory or storage	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/19 13:29
2	6305	(memory or storage) and resistance with cell with (high or low or on or off)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/19 13:31
3	13	((memory or storage) and resistance with cell with (high or low or on or off)) and reset$5 with cell with restor$5	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/19 13:43
4	9	((memory or storage) and resistance with cell with (high or low or on or off)) and reset$5 with cell with rewrit$5	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/19 13:53
5	33	(memory or storage) and compar$5 with resistance with cell with reference with (high or on)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/19 14:04
6	0	((memory or storage) and compar$5 with resistance with cell with reference with (high or on)) and (restor$5 or rewrit$5) with (origin$5 or initial$5)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/19 13:56
7	2	((memory or storage) and compar$5 with resistance with cell with reference with (high or on)) and (restor$5 or rewrit$5) with cell	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/19 14:05
9	0	((memory or storage) and compar$5 with resistance with cell with reference with (low or off)) and (restor$5 or rewrit$5) with cell	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/19 14:05
8	13	(memory or storage) and compar$5 with resistance with cell with reference with (low or off)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/19 14:25
10	34403	(memory or storage) and (pcram or program$5 adj product$5)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/19 15:10
11	395	((memory or storage) and (pcram or program$5 adj product$5)) and resistance with (high or on or state or level)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/19 14:28
12	0	(((memory or storage) and (pcram or program$5 adj product$5)) and resistance with (high or on or state or level)) and restor$5 with (initial$5 or origin$5) with resistance	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/19 14:28
13	6	(((memory or storage) and (pcram or program$5 adj product$5)) and resistance with (high or on or state or level)) and restor$5 with resistance	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/19 14:29
14	14	((memory or storage) and (pcram or program$5 adj product$5)) and (initial$5 or origin$5) with resistance with cell	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/19 15:05
15	5	(((memory or storage) and (pcram or program$5 adj product$5)) and (initial$5 or origin$5) with resistance with cell) and (restor$5 or rewrit$5 or reprogram$6)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/19 15:05

17	1	((memory or storage) and (pcram or program$5 adj product$5)) and restor$5 with (initial$5 or origin$5) with resistance	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/19 15:11
18	40	(memory or storage) and detect$5 with resistance with drift	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/19 15:13
19	2	((memory or storage) and detect$5 with resistance with drift) and restor$5 with resistance	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/19 15:14
20	0	(((memory or storage) and detect$5 with resistance with drift) and restor$5 with resistance) and cell	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/19 15:14